



Single Channel Type-1 M-LVDS to LVTTL Transceiver IDT5V5201

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Single Channel Type-1 M-LVDS to LVTTL Transceiver

IDT5V5201

FEATURES

◆ Main Features

- Up to 166 MHz LVTTL input/output signal
- M-LVDS interface allows common-mode voltage: -1 V to 3.4 V
- Power up and power down glitch free
- M-LVDS interface pins in high impedance state when the device is powered down or $VDD < 1.5$ V
- Capable of driving bus load from 30Ω to 55Ω

◆ Other Features

- Low power consumption < 120 mW
- Hot swappable
- 8-pin SOIC package

APPLICATIONS

- Backplane transmission
- Telecommunication system
- Data communications
- ATCA clock distribution

DESCRIPTION

The IDT5V5201 is a transceiver which can interchange data across multipoint data bus structures.

The device has a LVTTL driver and receiver, a selectable Type-1 M-LVDS receiver and M-LVDS driver. It translates between LVTTL signals

and M-LVDS signals. The drivers and the receivers can be enabled or disabled by external pins. The M-LVDS driver is capable of driving bus load from 30Ω to 55Ω . The M-LVDS interface allows common-mode voltage range of -1 V to 3.4 V.

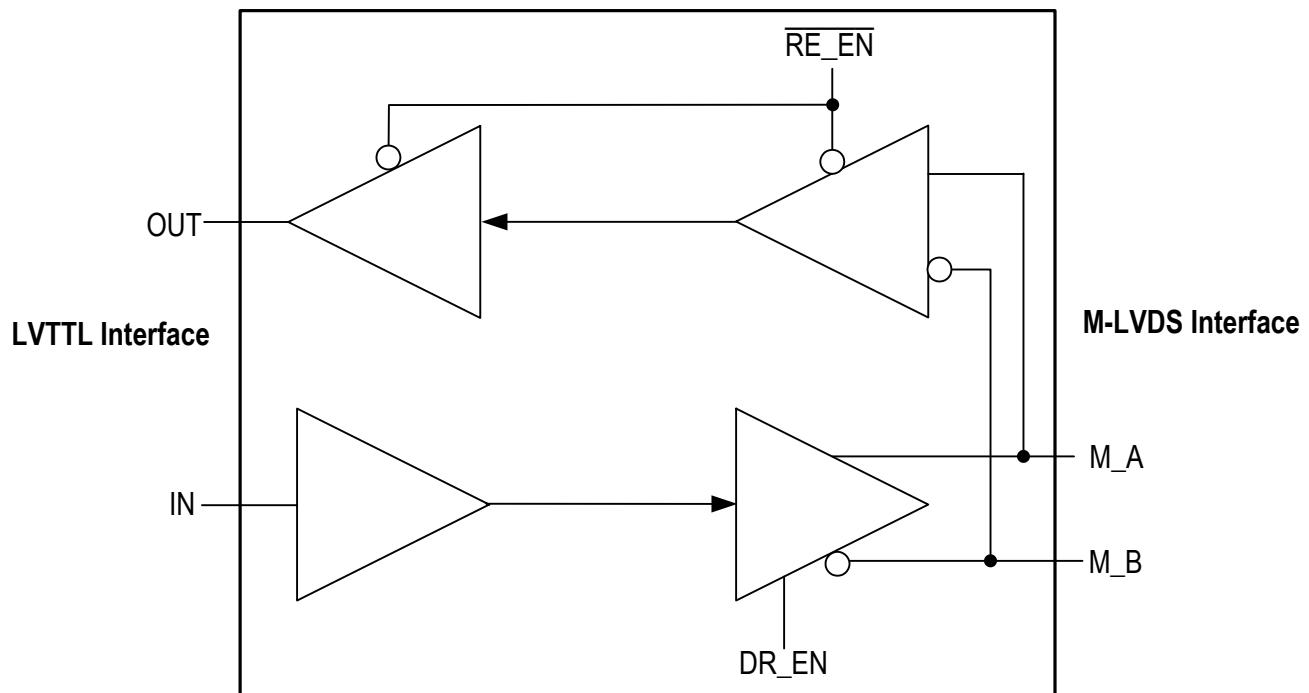
FUNCTIONAL BLOCK DIAGRAM

Figure-1 Functional Block Diagram

1 PIN ASSIGNMENT

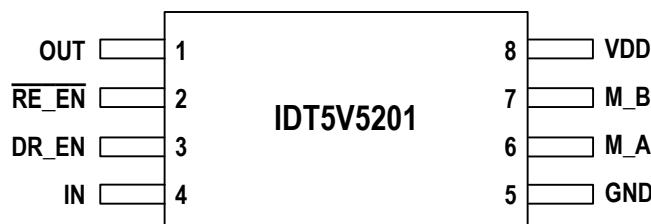


Figure-2 IDT5V5201 SOIC8 Package Pin Assignment

2 PIN DESCRIPTION

Table-1 Pin Description

Name	Pin No.	I/O	Type	Description
Global Signal				
DR_EN	3	 Pull-down	LVTTL	DR_EN: M-LVDS Driver Enable This pin controls the M-LVDS driver: high for enable and low for disable.
RE_EN	2	 Pull-up	LVTTL	RE_EN: Type-1 M-LVDS Receiver and LVTTL Driver Enable This pin controls the Type-1 M-LVDS receiver and LVTTL driver: high for disable and low for enable. Note that the LVTTL driver is in high impedance state when disabled.
LVTTL Interface				
IN	4		LVTTL	IN: LVTTL Input An up to 166 MHz LVTTL signal is input on this pin.
OUT	1	0	LVTTL	OUT: LVTTL Output This pin outputs an up to 166 MHz signal.
M-LVDS Interface				
M_A M_B	6 7	I/O	M-LVDS	M_A/M_B: Positive/Negative M-LVDS Data Bus Interface This pair of pins are connected to the M-LVDS data bus.
Power Supply and Ground				
VDD	8	Power	-	3.3 V Power Supply
GND	5	Ground	-	Ground

3 ELECTRICAL SPECIFICATION

3.1 ABSOLUTE MAXIMUM RATING AND RECOMMENDED OPERATION CONDITIONS

Table-2 Absolute Maximum Rating

Symbol	Parameter		Range	
V_{DD}	Supply Voltage		-0.5 V to 4.1 V	
V_{IN}	Input Voltage	$\overline{RE_EN}$, DR_EN, IN_A, IN_B	-0.5 V to 4.1 V	
		M_A, M_B	-1.8 V to 4 V	
V_{OUT}	Output Voltage	OUT_A, OUT_B	-0.3 V to 4 V	
		M_A, M_B	-1.8 V to 4 V	
	Electrostatic Discharge	Human Body Model M_A, M_B	± 8 kV	
		All pins	± 2 kV	
T_J	Junction Temperature	150°C		
T_S	Storage Temperature	-65°C to 165°C		

Table-3 Recommended Operation Conditions

Symbol	Parameter	Min	Typ	Max	Unit
V_{DD}	Power Supply	3.0	3.3	3.6	V
V_{IH}	High Level Input Voltage	2		3.0	V
V_{IL}	Low Level Input Voltage	0		0.8	V
	Voltage at any Bus Terminal	-1.4		3.8	V
	Magnitude of Differential Input Voltage	0.05		3.0	V
T_A	Ambient Operating Temperature	-40		85	°C

3.2 LVTTL DRIVER/RECEIVER CHARACTERISTICS

3.2.1 M-LVDS TO LVTTL

Table-4 LVTTL DC Parameters

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
V_{IHL}	Input High Level		2.0		$V_{DD} + 0.3$	V
V_{ILL}	Input Low Level		-0.3		0.8	V
I_{ILL}	Input Leakage Current		-1.0		1.0	μA
V_{OHL}	Output High Voltage	Output Current = 17 mA, $V_{DD} = 3$ V	2.4			V
V_{OLL}	Output Low Voltage	Output Current = 12 mA, $V_{DD} = 3$ V			0.4	V

Table-5 LVTTL AC Parameters

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
t_r	Rise Time	$C_{load} = 15 \text{ pF}, 10\% - 90\%$			1.2	ns
t_f	Fall Time	$C_{load} = 15 \text{ pF}, 10\% - 90\%$			1.2	ns
f_{ML}	Frequency				166	MHz

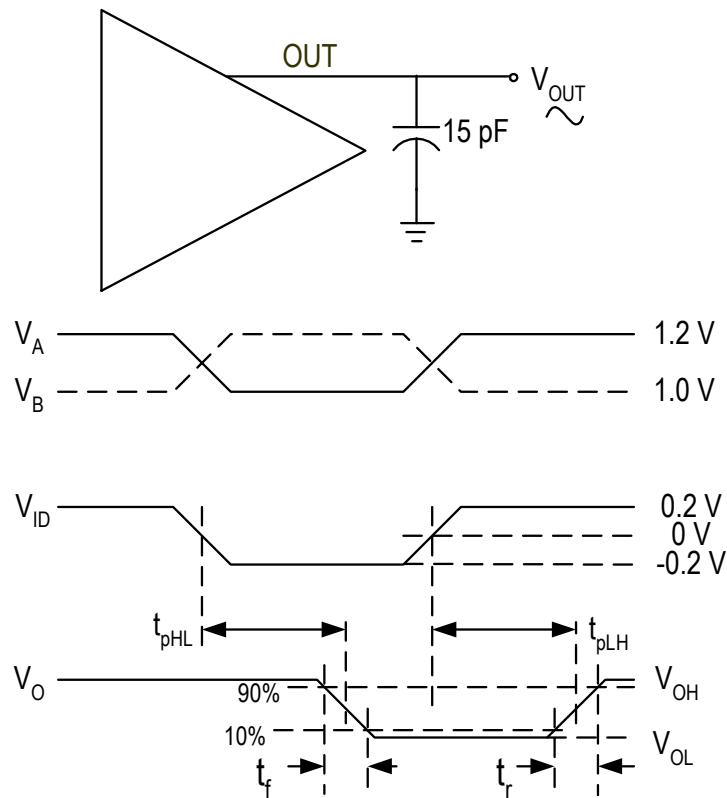


Figure-3 LVTTL Output Test Circuit and Waveforms

3.3 M-LVDS DRIVER TYPE-1 RECEIVER CHARACTERISTICS

Table-6 M-LVDS Type-1 Receiver Input Threshold Test Voltages

Applied Voltages		Resulting Differential Input Voltage	Resulting Common-mode Input Voltage	Receiver Output ⁽¹⁾
V _A	V _B			
2.400	0.000	2.400	1.200	High
0.000	2.400	-2.400	1.200	Low
3.425	3.375	0.050	3.4	High
3.375	3.425	-0.050	3.4	Low
-0.975	-1.025	0.050	-1	High
-1.025	-0.975	-0.050	-1	Low

¹. The receiver is enabled (The RE_EN pin is pulled low).

Table-7 M-LVDS DC Parameters

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
V_{ODM}	Differential Output Voltage		480		650	mV
ΔV_{ODM}	Change in V_{ODM} for Complementary Output States, $\Delta V_{ODM} = V_{ODM1} - V_{ODM0} $		-50		50	mV
V_{OSM}	Offset Voltage		0.8		1.2	V
ΔV_{OSM}	Change in V_{OSM} for Complementary Output States		-50		50	mV
$V_{OSM(p-p)}$	Peak-to-peak Common-mode Output Voltage				150	mV
I_{OM}	Output Short Circuit Current				20	mA
I_{IZM}	High Impedance Input Current		-10		10	μ A
V_{THM}	Differential Input High Threshold	Type-1	50			mV
V_{TLM}	Differential Input Low Threshold	Type-1			-50	mV
V_{CMM}	Input Common-mode Range	$V_{INA} - V_{INB} = 200$ mV	-1		3.4	V
I_{INM}	Input Current	Input Voltage = 0 V to 2.4 V	-20		20	μ A

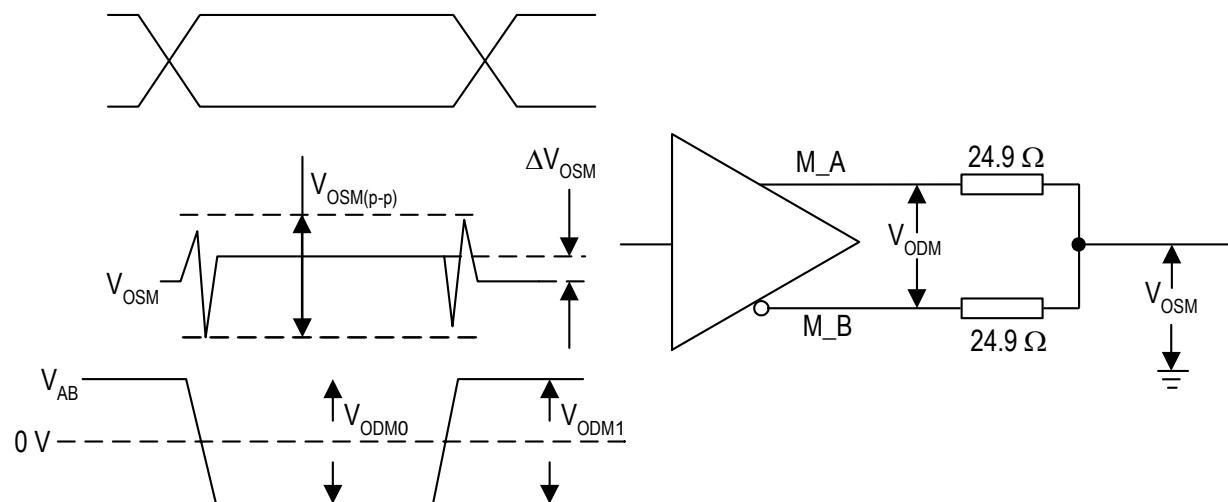


Figure-4 M-LVDS Driver Output Voltage Test Circuit

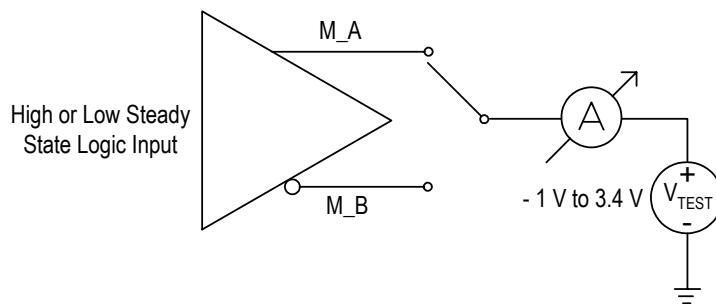


Figure-5 M-LVDS Driver Short-Circuit Test Circuit

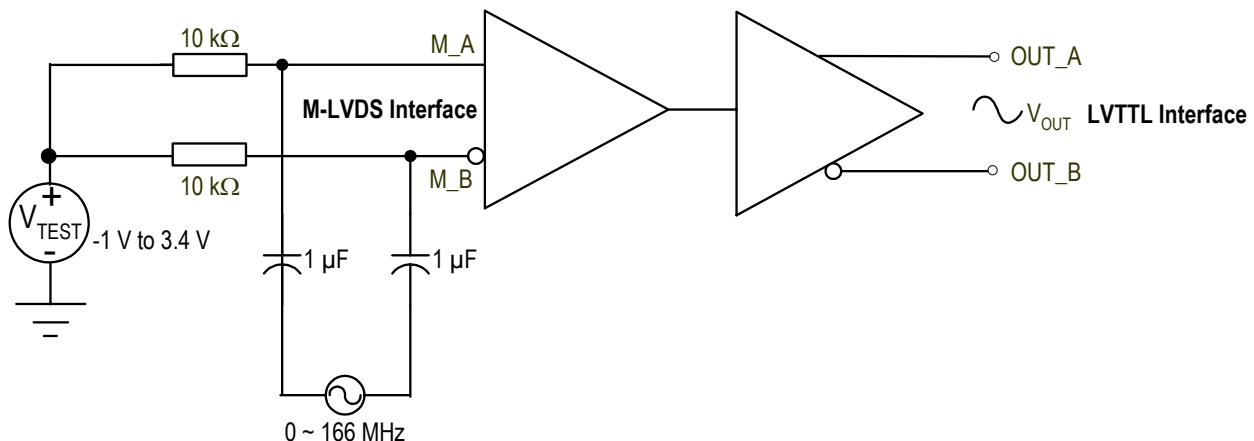


Figure-6 M-LVDS Type-1 Receiver Input Common-mode Range Test Circuit

Table-8 M-LVDS Input Current Parameters

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
I_A	Receiver or Transceiver with Driver Disabled Input Current	$V_A = 3.8 \text{ V}, V_B = 1.2 \text{ V}$	0		32	μA
		$V_A = 0 \text{ V} \text{ or } 2.4 \text{ V}, V_B = 1.2 \text{ V}$	-20		20	
		$V_A = -1.4 \text{ V}, V_B = 1.2 \text{ V}$	-32		0	
I_B	Receiver or Transceiver with Driver Disabled Input Current	$V_B = 3.8 \text{ V}, V_A = 1.2 \text{ V}$	0		32	μA
		$V_B = 0 \text{ V} \text{ or } 2.4 \text{ V}, V_A = 1.2 \text{ V}$	-20		20	
		$V_B = -1.4 \text{ V}, V_A = 1.2 \text{ V}$	-32		0	
I_{AB}	Receiver or Transceiver with Driver Differential Current ($I_A - I_B$)	$V_A = V_B, -1.4 \text{ V} < V_A < 3.8 \text{ V}$	-4		4	μA
$I_{A(OFF)}$	Receiver or Transceiver Power-off Input Current	$V_A = 3.8 \text{ V}, V_B = 1.2 \text{ V}, 0 \text{ V} < V_{DD} < 1.5 \text{ V}$	0		32	μA
		$V_A = 0 \text{ or } 2.4 \text{ V}, V_B = 1.2 \text{ V}, 0 \text{ V} < V_{DD} < 1.5 \text{ V}$	-20		20	
		$V_A = -1.4 \text{ V}, V_B = 1.2 \text{ V}, 0 \text{ V} < V_{DD} < 1.5 \text{ V}$	-32		0	
$I_{B(OFF)}$	Receiver or Transceiver Power-off Input Current	$V_B = 3.8 \text{ V}, V_A = 1.2 \text{ V}, 0 \text{ V} < V_{DD} < 1.5 \text{ V}$	0		32	μA
		$V_B = 0 \text{ or } 2.4 \text{ V}, V_A = 1.2 \text{ V}, 0 \text{ V} < V_{DD} < 1.5 \text{ V}$	-20		20	
		$V_B = -1.4 \text{ V}, V_A = 1.2 \text{ V}, 0 \text{ V} < V_{DD} < 1.5 \text{ V}$	-32		0	
$I_{AB(OFF)}$	Receiver or Transceiver Power-off Differential Input Current ($I_A - I_B$)	$V_A = V_B, 0 \text{ V} < V_{DD} < 1.5 \text{ V}, -1.4 \text{ V} < V_A < 3.8 \text{ V}$	-4		4	μA
C_{AB}	Transceiver with driver disabled differential input capacitance	$V_{AB} = 0.4 \sin(30E6\pi t) \text{ V}$			4	pF

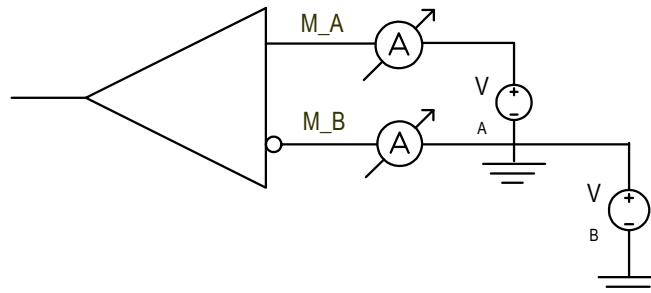
**Figure-7 Various Input Currents Test Circuit**

Table-9 M-LVDS AC Parameters

Symbol	Parameter	Test Conditions	Min.	Typ	Max.	Unit
t_r	Rise Time	10% - 90%	0.8		1.5	ns
t_f	Fall Time	10% - 90%	0.8		1.5	ns
t_{TSL}	Differential Skew, $t_{TSL} = \{t_{TSL1}, t_{TSL2}\}$		-100		100	ps
f_{ML}	Frequency				166	MHz

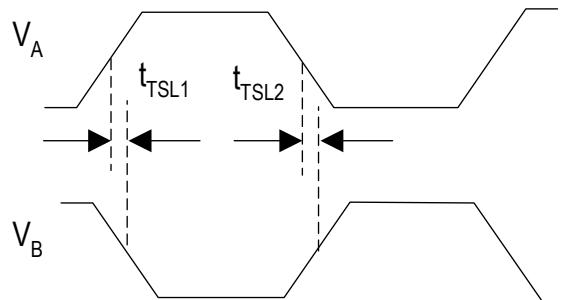


Figure-8 Differential Skew

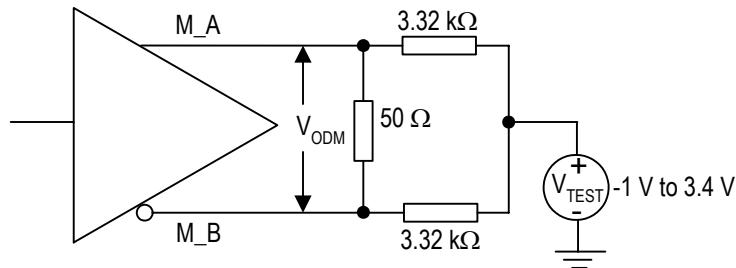


Figure-9 M-LVDS Output Voltage Test Circuit

Table-10 M-LVDS Type-1 Receiver AC Parameters

Output mode	Symbol	Parameter	Test Condition	Min	Typ	Max	Unit
LVTTL	t_{pLH}	Delay, Low to High Level	Input clock: freq = 50 MHz, Impedance = 150Ω , Voltage = -200 mV - 200 mV. See Figure-3	2.5	5.5	6.5	ns
	t_{pHL}	Delay, High to Low Level		2.5	5.5	6.5	ns
	t_{sk}	Type-1 Pulse Skew, $t_{sk} = t_{pLH} - t_{pHL} $			100	300	ps
	T_r (10% - 90%)	Rise Time		1		2.4	ns
	T_f (10% - 90%)	Fall Time		1		2.4	ns
	T_{jitter} (per)	Period jitter, rms(1 standard deviation)			4	7	ps
		Output to Output Skew				200	ps

Table-11 M-LVDS Driver AC Parameter

Symbol	Parameter	Test Condition	Min	Typ	Max	Unit
t_{pLH}	Delay, Low to High Level	Input clock: freq = 15 MHz, $T_r = T_f = 1.2$ ns, Impedance = 300Ω , Voltage = 0 V - 3.3 V. See Figure-4	2.5	3.7	5.5	ns
t_{pHL}	Delay, High to Low Level		2.5	3.7	5.5	ns
t_{sk}	Pulse Skew, $t_{sk} = t_{pLH} - t_{pHL} $			40	100	ps
T_r (10% - 90%)	Rise Time		0.7	1.1	1.5	ns
T_f (10% - 90%)	Fall Time		0.7	1.1	1.5	ns
T_{jitter} (per)	Period jitter, rms(1 standard deviation)			2	3	ps
	Output to Output Skew				100	ps

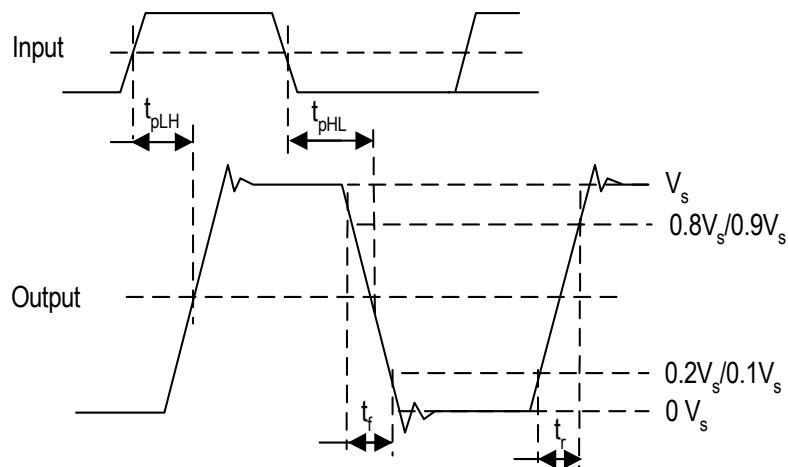
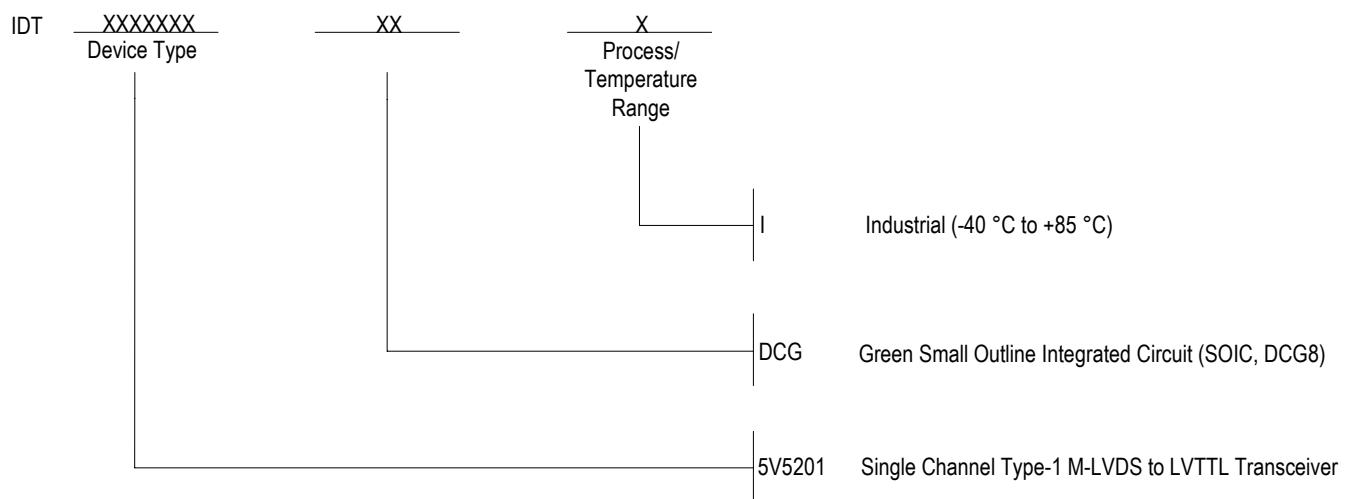


Figure-10 Timing and Voltage Definitions for the Output Signal

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